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Enhanced photoelectrochemical response of 1D TiO$_2$ by atmospheric pressure plasma surface modification

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**HIGHLIGHTS**

- 1D TNRs treated with atmospheric pressure plasma jet (APPJ) at room temperature.
- A four-fold enhancement in the photocurrent after the He-APPJ functionalization.
- PEC performance improved, on par with the best in the literature.

**ABSTRACT**

In this paper we demonstrate the use of atmospheric pressure plasma jet (APPJ) to functionalize the surface of hydrothermally synthesized vertically aligned TiO$_2$ nanorods (TNRs) for photo electrochemical (PEC) application. The TNRs functionalized with the atmospheric pressure He-plasma showed relatively higher crystallinity, improved light absorption, and change in the morphology with additional surface area, leading to an enhanced photocurrent density than that of the untreated. Achieving the PEC performance on par with the best in the literature, this APPJ treatment is shown to be a promising technique to obtain better functionality with TNR kind of materials and many other nano-micro systems for various applications such as PEC hydrogen generation.

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Introduction

TiO₂ has been widely explored for thin film solar cells [1], photocatalytic H₂ evolution [2], photoelectrochemical (PEC) water splitting [3], self-cleaning and antifogging applications [4] due to its optical and electronic properties along with the nontoxicity, economical, chemical stability, and anticorrosive characteristics [5]. TiO₂ finds valuable applications in LEDs, as photo-anode in new photovoltaic devices, photo-electrochemical cells, water splitting, and in gas sensors & heat reflectors [6–12]. Of particular interest are, one-dimensional TiO₂ nanorod (TNR) arrays fabricated by a simple and economical hydrothermal method [13], found to have a superior chemical stability and high electron mobility [14,15] that are required for all the above applications. Furthermore, for solar energy applications, the vertical alignment of nanorods on a substrate can offer improved absorption of light due to the diffuse reflection happening between the nanorod arrays. Also, such structures offer a direct and efficient transport pathway for the photo-generated electrons. Altogether, these features are expected to enhance the carrier generation, their separation, and transport in solar energy conversion devices [16]. However, the wide band-gap of the TiO₂ (3.2 eV) limits its light-absorption only to the UV range, which is only a small part of the solar spectrum [17]. Hence, bandgap engineering of TiO₂ has been explored through metal, non-metal doping [18], and also metal doping with Ar, N₂, & O₂ plasma treatment [19] to improve the absorption of the solar radiation. Such efforts on improving the optical properties of TiO₂ film with & without doping have been made by employing the plasma treatment technique [20]. In another way, many methods for its surface modification have been practiced including surface hydrogenation, vacuum activation and plasma treatment [21–23]. The plasma treatment cover’s a very broad range of different plasma techniques based on the operating pressure (low and atmospheric), thermodynamics (thermal and non-thermal), temperature (low and high), source of plasma (Microwave discharge, DC discharge, dielectric barrier discharge, corona discharge, AC arc discharge, electron beam, plasma torch, glow discharge, hollow cathode discharge) [24–36].

Among them, non-thermal and atmospheric pressure plasmas have grown to be of huge scientific and commercial importance for materials processing due to their simple cost effective nature and ability to bring in rich chemical as well as physical properties [37,38]. Plasma treatment technique has been the most versatile surface treatment [39–42] based on a few of its advantages namely; (i) the air plasma treatment removes organic impurities absorbed on the surface of TiO₂, (ii) formation of hydroxyl group on the surface during the plasma treatment to improve wettability [43], and (iii) oxygen vacancies might serve as the trap centers for photo-generated electrons and suppress the recombination. Hence, the electron-hole pairs could be separated and transported more effectively [44]. For example, the plasma treatment of TNRs with reactive gases such as H₂, N₂, and O₂ has been explored and an improved the PCE efficiency from 0.62% (untreated) to 1.11% (N₂ plasma-treated) of DSSCs [45].

Several efforts were made to improve the PEC activity of TiO₂ nanostructures. TiO₂ nanoparticle layer synthesized on Ti foil via the potentiostatic anodization method showed a PEC current density of 2 μAcm⁻² and further improved up to 40 μA cm⁻² after combining it with CuO [46]. The photocurrent density up to 1 mA cm⁻² was achieved with TiO₂ nanoporous photoelectrodes with mixed anatase and rutile phases by a dip-coating and subsequent calcination process [47]. Further, the PEC performance of TiO₂ was also improved by doping such as Fe, Ni, Mn, Cr, Si, Co [48–51]. Particularly, Fe doped TiO₂ nanoparticles exhibited a photocurrent density of 54 μA cm⁻², which was 3.6 times higher than that of undoped TiO₂ nanoparticles [52]. Peng et al. reported the N-doped TiO₂ (P25 Degussa) for photoelectrochemical CO₂ reduction and achieved the maximum current density of 0.104 mA cm⁻² at 2 V (vs. SCE) [53]. N doping of anatase and rutile phase TiO₂ nanowires also improved the PEC performance [54,55]. The activity of TNRs was improved up to 1.25, 2.0, 1.53 μAcm⁻² (vs. Ag/AgCl) and 0.81 μA cm⁻² (vs. RHE), by doping of C, Sn, W and Si [56–59]. The hydrogenation of TNR via rapid thermal annealing (RTA) process was also explored for PEC H₂ evolution. The highest photocurrent of 3.7 μA cm⁻² was obtained using TNRs treated with RTA at 400 °C for 1 h [60].

Few of such efforts to improve the PEC performance of TiO₂ were involving the conventional plasma. The TiO₂ nanotubes treated under vacuum with air plasma for 20 min also showed a stable & improved photocurrent density (2.4 μA cm⁻² vs. RHE) [43]. The TiO₂ thin film deposited by the atomic layer deposition method showed enhancement in the PEC current density from 0.12 to 1 mA cm⁻² after hydrogen plasma treatment [61]. TiO₂ nanosheets plasma-treated using a plasma cleaner under Ar atmosphere showed the current density of 43.7 μA cm⁻² (vs. Ag/AgCl) under 300 W Xenon arc lamp with an AM 1.5 filter [62]. In another report, after incorporation of hydrogen by H₂ plasma treatment, the mesoporous TiO₂ films showed the current densities of 22.9 μA cm⁻² & 0.16 μA cm⁻² under UV-LED & Blue-LED respectively [63]. Thus, in general, the conventional plasma treatment was already proved to be an effective technique to improve the PEC performance of TiO₂. The plasma treatment is also known to improve the functional properties in many other materials as well [64–66] and for example, it has also been reported that helium (He) plasma treatment is a promising method to reduce the contact resistance of source/drain region for Indium–Gallium–Zinc oxide (IGZO) thin film transistors [64] due to the formation of oxygen vacancies [65].

One-dimensional TNRs could offer an advantageous conducting network because of their short electron pathway as discussed in the works of literature [16]. Thus, it was expected that the nanorods would show a better PEC performance with higher photocurrent density. However, it can be also observed from the literature that they generally showed relatively inferior PEC activity with lower photocurrent, probably due to the lower crystallinity, higher contact angle with water, as well as due to the absence of surface defect states. Few efforts, as mentioned above, were made to overcome these limitations and to improve the PEC performance of TNRs. However,
most of these efforts used the plasma treatment process under vacuum and high temperature conditions. As reported, the low-power atmospheric pressure plasma jet (APPJ) is an easily scalable, non-thermal technique to improve the electronic properties of many functional materials [67–69]. Presently, there has been an increasing interest for APPJ in materials processing, as there is no requirement for sophisticated vacuum equipment and high temperatures which makes it cost effective [38,69]. Additionally, plasma jets can be directed towards substrated, hence can be used remotely suitable for industrial applications. APPJ is known to control the defects, crystallinity, and surface wettability [68–70]. APPJs can deliver transient electric fields along with charged particles, neutral metastable species, radicals, and radiation plume [68,71]. To overcome the small area covered by the plasma jet on the substrate, several approaches have been reported so far, e.g. array of plasma jet or by varying the distance between the jet and the substrate was maintained at 5 mm during the exposure for 5 min.

Characterization

The X-ray diffraction was carried out using Cu Kα radiation (BRUKER USA D8 Advance, Davinci, wavelength = 1.5405 Å) with the diffraction angle from 10° to 80°. Absorption studies were carried out with the ultraviolet-diffuse reflectance spectroscopy (UV-DRS) by using Agilent-Cary (Cary 5000 UV–Vis–NIR) spectrophotometer. Raman spectra were recorded using Micro Raman spectrometer (HORIBA France, LABRAM HR Evolution) with a 532 nm laser wavelength. The surface morphology of the film was studied by using a high-resolution Scanning Electron Microscope (F E I Quanta FEG 200). Water contact angle measuring instrument (HO-IAD-CAM-01) was used in this study to measure the wettability of TNR substrates before and after AP treatment. 1 mL of deionized water was dispensed for each measurement. The photoelectrochemical measurements of the TNR samples were recorded using CHI604E potentiostat with the scan rate of 50 mV/s and a scanning range of −1.0 V–1.5 V. Photo-electrochemical cell had the platinum, Ag/AgCl, and TiO2/FTO films used as a counter, reference, and working electrodes respectively. 0.1 M NaOH was used as the electrolyte throughout measurements and the light from a PET (Photo Emission Tech, Inc. USA, 300WSS-EM) solar simulator with power 100 mW/cm² was used for illumination under 1.5 AM filter.

Results and discussion

Structural and morphological study

Fig. 1(a) shows that the XRD patterns of TNR, TNR (He), TNR (He + O₂), and TNR (He + N₂) films were in accordance with the standard data for TiO₂ (space group; P42/mnm) as provided by JCPDS (Joint Committee on Powder Diffraction Standards), reference: 01-078-1510, thereby confirming tetragonal rutile phase of TiO₂. All the films exhibited crystalline nature having the most intense peak consistent to (101) plane of TiO₂. Six more peaks corresponding to (110), (200), (111), (211), (002), (221), (112) and (301) planes were also observed. No peaks were observed corresponding to anatase or brookite phase indicating the high purity of the rutile TNR samples. The crystallite size (D) was estimated by using Debye–Scherrer formula,

\[ D = \frac{0.9 \lambda}{\beta \cos \theta} \]

where, λ - 0.15418 nm, β - full width at half maximum (FWHM), and θ - Bragg’s angle in degree. Fig. 1(b) shows the overlay spectra of (101) plane and we estimated 2θ values (36.26°,
FWHM (0.3085°, 0.1278°, 0.1299° & 0.2996°) for (101) plane of TiO₂ (TNR, TNR (He), TNR (He + O₂), & TNR (He + N₂)). The observed shift in 2θ values with respect to the untreated TNR was about 0.28°, 0.01° & 0.03° after He, (He + O₂), & (He + N₂) APPJ treatments respectively. The shift in the 2θ values can be attributed to the stress on the lattice caused due to the pressure exerted by the reactive gas used for the APPJ treatment. The calculated crystalline sizes for TNR, TNR (He), TNR (He + O₂), and TNR (He + N₂) films were 28.31, 68.29, 67.24, and 29.10 nm respectively. It can be noticed that the APPJ treatment caused observable changes in the crystalline size. He and He + O₂ plasma-treated samples showed bigger size crystals, more than double in size, as compared to the He + N₂ APPJ treated and untreated TNRs. This effect is similar to the observation with N₂ plasma-treated TiO₂ nanoparticles in the literature [78]. The increase in the crystalline size indicates the improvement in the crystallinity of TNRs and also can be related to the formation of intrinsic defects on the surface of TiO₂ itself referring to the similar observations in the literature [79]. The improved crystallinity with the formation of intrinsic defects after He and (He + O₂) APPJ treatment may lead to an improved PEC activity [80–82].

Optical study

The UV–visible absorbance spectra of treated and untreated TNR films over the wavelength range of from 300 to 900 nm is shown in Fig. 3(a). The bandgap of the TNR films has been determined using the relation,

\[ a = A \left( \frac{\hbar \nu}{E_g} \right)^{\frac{1}{2}} \]

where, \( a \) is the absorption coefficient, \( A \) is the constant, \( E_g \) is the energy gap and \( \hbar \nu \) is the incident photon energy. The values of bandgap were estimated from the Tauc plots (inset of Fig. 3(a)) as 3.24, 3.22, 3.25, and 3.19 eV for the TNR, TNR
(He), TNR (He + O₂), and TNR (He + N₂) films respectively, which are in accordance with the previous reports [86,87].

It can be observed that the absorption edge was shifted to higher wavelength (red shift) and the bandgap was reduced for TNR (He) as well as TNR (He + N₂) samples. In contrast, there was an increase in the bandgap (blue shift) for TNR (He + O₂). The possibility for such variation in the band edge after plasma treatment of TiO₂ is indicated in the literature and our results are in accordance with the same [20]. The plasma treatment was used as an effective technique to decrease the bandgap of TiO₂ and to promote the formation of defect states by introducing the oxygen vacancies [62], both of which could improve the UV–visible light absorption [88,89]. Similar changes observed in our UV–visible absorption spectra of TNRs after the He and (He + N₂) APP treatment, where there was an improved absorption and red shift of band edge [65,66] indicating the formation of oxygen vacancy defect states unlike in the case of (He + O₂) APP treatment. These changes observed in the UV–visible light absorption after the He and (He + N₂) APP treatment also indicate improved PEC activity, analogous to the earlier observation in the literature [62].

Fig. 2 – Schematic of the He-APP treatment of the TNR films.

Fig. 3 (a) UV–visible spectra with (inset) Tauc plot and (b) Raman spectra with an overlay of Raman spectra for A₁g & E₉ modes of the TNR, TNR (He), TNR (He + O₂), and TNR (He + N₂) films. Fig. 3 (b) shows the Raman spectra of the TNR, TNR (He), and TNR (He + O₂) films. Raman spectra of all the samples confirmed the formation of the rutile phase of TiO₂. There are five Raman active modes namely A₁g, B₁g, B₂g, E₉, and multiphoton process mode for rutile TiO₂ [76,88,90], which appear around at 611 cm⁻¹, 143 cm⁻¹, 830 cm⁻¹, 447 cm⁻¹, and 240 cm⁻¹ respectively. The two prominent maxima at 447 cm⁻¹ (E₉) and 611 cm⁻¹ (A₁g) are in accordance with literature for rutile TiO₂ [76,91]. The A₁g peak position (Fig (b) inset) for TNR, TNR (He), TNR (He + O₂), and TNR (He + N₂) films appeared at 611.10, 609.16, 610.07, and 611.10 cm⁻¹ with FWHM 27.42, 26.50, 28.75 and 38.86 cm⁻¹. Also, the E₉ peak position (Fig (b) inset) appeared at 447.72, 445.23, 445.23 and 23.24 cm⁻¹ for TNR, TNR (He), TNR (He + O₂), and TNR (He + N₂) films respectively. The decrement in the FWHM of A₁g and E₉ peaks indicated that the increment in the crystallinity of TNR after He APP, in concurrence with their XRD result as well as the literature report [76].

Surface wettability, as one of the fundamental surface properties of an electrode, could show significant influence on its functionalities such as electrolyte-wetting, redox electron
transfer and gas release in electrochemical reactions [92–97]. It is known that a hydrophilic surface leads to better electron transfer rate between electrolyte and electrode [94]. The surface plasma treatment also improves the wettability of the TiO₂ photoanode by forming hydroxyl groups and could contribute to the enhancement of PEC performance [43]. Expecting the similar effect, we have performed the wettability test of untreated and APPJ treated TiO₂ NRs with water, and the results are shown in Fig. 51 (Supporting information). The contact angles of the water droplet for the APPJ treated TiO₂ NRs were smaller than that for the untreated TiO₂ NRs. He APPJ treatment showed a small change in wettability, and further optimization of plasma treatment conditions may be needed to achieve the hydrophilic nature of the TNR films. Lee et al. had observed a significant improvement in wettability of Ti substrate after plasma treatment by using He and O₂/He mixture carrier gases [98]. Similarly, in our case wettability has improved after (He + O₂) & (He + N₂) APPJ treatment with a switch from hydrophobic to hydrophilic nature.

PEC measurements of TiO₂ films

Fig. 4(a) shows the linear sweep voltammogram (LSV) curves of the treated and untreated TNR samples in dark and under illumination. The maximum current density at 0 V (Ag/AgCl) observed for the TNR, TNR (He), TNR (He + O₂), and TNR (He + N₂) were 0.1964, 0.8715, 0.0079, and 0.7450 mAcm⁻² respectively. Further, chronoamperometry measurement was performed to check the stability and reproducibility of the photoanode. The measurement was carried out with 5 on-off cycles of 10 s time interval, in a similar manner as reported earlier on PEC devices [62,99]. Fig. 4(b) revealed the good reproducibility & stability of the current density with time. All treated and untreated TNR films were observed to be stable after 5 on-off cycles with a time duration of 10 s at 0.4 V (Ag/AgCl). We observed almost 4 times enhancement in the maximum current density for TNR (He) film as compared to untreated TNR under the light. At fixed potentials the electrodes usually adopt a steady dark current. In our case, we could observe that the current reached a sharp maximum (the current spike) immediately after switching on the light. This might be attributed to the rapid initial separation of electron/hole pairs or to the presence of the high initial concentration of negative charge carriers accumulated in the film during the deposition [100]. Such spikes are known to arise due to the electron recombination with surface-trapped holes or photo-oxidation intermediates [101].

Based on our observations, this enhancement in the current density of the He-treated TNRs can be ascribed to the higher crystallinity, reduced bad gap, availability of additional surface area, and the possible formation of oxygen vacancy defect states in the TNRs. However, the TNR sample treated

<table>
<thead>
<tr>
<th>TiO₂</th>
<th>Plasma modification</th>
<th>Max. Photocurrent density (mAcm⁻²)</th>
<th>Reference</th>
</tr>
</thead>
<tbody>
<tr>
<td>ALD grown planar TiO₂</td>
<td>As prepared</td>
<td>0.12 (0.8 V vs NHE)</td>
<td>[61]</td>
</tr>
<tr>
<td></td>
<td>Hydrogen plasma for 1 h at 200 °C</td>
<td>1.0 (0.8 V vs NHE)</td>
<td></td>
</tr>
<tr>
<td>TiO₂ nanosheet</td>
<td>As prepared</td>
<td>0.113 (0.6 V vs Ag/AgCl)</td>
<td>[62]</td>
</tr>
<tr>
<td></td>
<td>Argon plasma for 2 h at 40 Pa</td>
<td>0.0437 (0.6 V vs Ag/AgCl)</td>
<td></td>
</tr>
<tr>
<td>Mesoporous TiO₂</td>
<td>As prepared</td>
<td>0.00081 (0.4 V vs Ag/AgCl)</td>
<td>[63]</td>
</tr>
<tr>
<td></td>
<td>Hydrogen plasma for 5 min at 60 mTorr</td>
<td>0.0229 (0.4 V vs Ag/AgCl)</td>
<td></td>
</tr>
<tr>
<td>TiO₂ nanorods</td>
<td>As prepared</td>
<td>0.1964 (0 V vs Ag/AgCl)</td>
<td>This work</td>
</tr>
<tr>
<td></td>
<td>Helium atmospheric pressure plasma for 5 min</td>
<td>0.8715 (0 V vs Ag/AgCl)</td>
<td></td>
</tr>
<tr>
<td></td>
<td>(Helium + Oxygen) atmospheric pressure plasma for 5 min</td>
<td>0.0079 (0 V vs Ag/AgCl)</td>
<td></td>
</tr>
<tr>
<td></td>
<td>(Helium + Nitrogen) atmospheric pressure plasma for 5 min</td>
<td>0.7450 (0 V vs Ag/AgCl)</td>
<td></td>
</tr>
</tbody>
</table>

Fig. 4 – (a) Linear sweep voltammogram (LSV) curves and (b) Results from a chronoamperometry measurement of TNR, TNR (He), TNR (He + O₂), and TNR (He + N₂) films under light chopping for 10 s.
with (He + O₂) showed very less current density compared to all others, which may be due to the absence of oxygen vacancy defect states as indicated by the UV–visible absorption studies. Also, due to the lower crystallinity, as shown by the XRD & Raman results, TNR (He + N₂) samples exhibited lower current density compared to the TNR (He).

The results obtained are comparable with the previous reports in the literature (Table 1). It is noteworthy that the PEC activity of He plasma surface-modified TNRs was comparable to the best in the literature using ALD grown Hydrogen plasma-treated planar TiO₂. The photocurrent density shown by the He APPJ treated TNRs is the second-highest reported so far for TiO₂ and there is room for further improvement by optimization or employing the plasma of other carrier gases. The improvement in the PEC performance could be correlated with our observations on (i) the availability of surplus surface area of TNRs to interact with the electrolyte, (ii) the increase in the crystalline size, accompanied by the possible formation of more intrinsic defects in TNRs and (iii) reduction in the bandgap which improved the UV–visible light absorption.

**Conclusion**

In summary, surface functionalization of TNRs was achieved using the simple, room temperature atmospheric pressure plasma treatment technique. The effect of APP treatment on the structural, optical, and PEC properties of TNRs was established. A four-fold enhancement in the photocurrent was observed after the He-APPJ treatment of TNRs, and this performance is on par with the best in the literature using the conventional hydrogen plasma-treated ALD grown planar TiO₂. The improvement in the PEC performance could be correlated with our observations on (i) the availability of surplus surface area of TNRs to interact with the electrolyte, (ii) the increase in the crystalline size, accompanied by the possible formation of more intrinsic defects in TNRs and (iii) reduction in the bandgap which improved the UV–visible light absorption.

**Data availability statement**

The raw/processed data required to reproduce these findings cannot be shared at this time as the data also forms part of an ongoing study.

**Declaration of competing interest**

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

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**Appendix A. Supplementary data**

Supplementary data to this article can be found online at https://doi.org/10.1016/j.ijhydene.2021.01.142.

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